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TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP185

Office Machine Programmable Controllers Unit: mm AC Adapter I/O Interface Board The TOSHIBA mini flat coupler TLP185 is a small outline coupler, suitable for surface mount assembly. TLP185 consists of a photo transistor optically coupled to a gallium arsenide infrared emitting diode. Since TLP185 is smaller than DIP package, it's suitable for high-density surface mounting applications such as programmable controllers. 7.0±0.4 Collector-emitter voltage: 80 V (min) Current transfer ratio: 50 % (min) Rank GB: 100% (min) Isolation voltage: 3750 Vrms (min) Operation Temperature:-55 to 110 °C Safety Standards UL approved: UL1577, File No. E67349 TOSHIBA 11-4M1S cUL approved: CSA Component Acceptance Service No. 5A Weight: 0.08 g (typ.) File No.E67349 CQC approved:GB4943.1,GB8898 Japan and Thailand Factory ④ COC 仅适用干海拔 2000m 以下地区安全使用 Option (V4) type VDE approved: EN60747-5-5, EN60065, EN60950-1 (Note 1) Pin Configuration (top view) Under application EN62368-1 Note 1: When a EN60747-5-5 approved type is needed, Please designate "Option(V4)" 1[Construction mechanical rating Creepage distance : 5.0 mm (min) Clearance : 5.0 mm (min) : 0.4 mm (min) Insulation thickness 1: Anode 3: Cathode 4: Emitter

6: Collector

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Current Transfer Ratio

| | | Current Transfer | Ratio (%) (I _C / I _F) | | | | |
|---------|---------------------------|--|--|---------------------------------|--|--|--|
| Туре | Classification (Note1) | I _F = 5 mA, V _{CE} | = 5 V, Ta = 25°C | Marking Of Classification | | | |
| | | Min | Max | \sim | | | |
| | Blank | 50 | 400 | Blank, YE, GR, GB, Y+, G, G+, B | | | |
| | Rank Y | 50 | 150 | YE , Y+ | | | |
| | Rank GR | 100 | 300 | GR , G ,G+ | | | |
| TLP185 | Rank GB | 100 | 400 | GB, GR, G, G+, BL, B, | | | |
| ILP 100 | Rank YH | 75 | 150 | Y+ | | | |
| | Rank GRL | 100 | 200 | G | | | |
| | Rank GRH | 150 | 300 | G+ | | | |
| | Rank BLL | 200 | 400 | в 20 | | | |

Note1: Ex Rank GB: TLP185 (GB,E

Note: Application, type name for certification test, please use standard product type name, i, e. TLP185(GB,E: TLP185

Absolute Maximum Ratings (Ta = 25°C)

| | Characteristic | Symbol | Rating | Unit | |
|----------|---|---------------------|------------|----------|-------------------|
| | Forward current | lF | 50 | mA | |
| | Forward current derating (Ta ≥ 90°C) | ΔIF/°C | -1.5 | mA/°C | |
| | Pulse forward current (Note 1) | IFP | 1 | A | |
| LED | Reverse voltage | VR | 5 | X | |
| _ | Diode power dissipation | PD | 100 | mW | |
| | Diode power dissipation derating (Ta >90°C) | ∆P _D /°C | -2.9 | mW/°C | |
| | Junction temperature | Tj | 125 |)) °C | |
| | Collector-emitter voltage | VCEO | 80 | V | |
| | Emitter-collector voltage | VECO | | V | |
| Detector | Collector current | Ic | 50 | mA | |
| Dete | Collector power dissipation | Pc | 150 | mVV | |
| | Collector power dissipation derating $(Ta \ge 25^{\circ}C)$ | ΔPc/°C | -1.5 | mW/°C | $\langle \rangle$ |
| | Junction temperature | Тј |) 125 🛇 | °C |) |
| Оре | erating temperature range | Topr | -55 to 110 | <u>с</u> | |
| Stor | rage temperature range | Tstg | -55 to 125 | °C | |
| Lea | d soldering temperature (10 s) | T _{sol} | 260 | C₀C | |
| Tota | al package power dissipation | PT | 200 | mW | |
| Tota | al package power dissipation derating (Ta \ge 25°C) | ΔΡτ/°C | -2.0 | mW/°C | |
| Isola | ation voltage (AC, 60 s, R.H. ≤ 60%) (Note 2) | BVs | 3750 | Vrms | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width \leq 100 µs, f = 100 Hz

Note 2: Device considered a two terminal device: Pins 1 and 3 shorted together and 4 and 6 shorted together.

Recommended Operating Conditions

| Characteristic | Symbol | Min | Тур. | Max | Unit |
|-------------------|--------|-----|------|-----|------|
| Supply voltage | Vcc | _ | 5 | 48 | V |
| Forward current | IF | _ | 16 | 20 | mA |
| Collector current | lc | _ | 1 | 10 | mA |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

| | Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------|-------------------------------------|-----------------|-----------------------------------|-----|------|------|------|
| | Forward voltage | VF | IF = 10 mA | 1.1 | 1.25 | 1.4 | V |
| LED | Reverse current | IR | VR = 5 V | — | — | 5 | μA |
| | Capacitance | CT | V = 0 V, f = 1 MHz | X | 30 | — | pF |
| | Collector-emitter breakdown voltage | V(BR)CEO | IC = 0.5 mA | 80 | | — | V |
| or | Emitter-collector breakdown voltage | V(BR)ECO | IE = 0.1 mA | X |)/ | — | V |
| Detector | Collector dark current ICEO | 1 | VCE = 48 V | 77 | 0.01 | 0.08 | μA |
| | | ICEO | V _{CE} = 48 V, Ta = 85°C | H | 2 | 50 | μA |
| | Capacitance (collector to emitter) | C _{CE} | V = 0 V, f = 1 MHz | | 10 | _ | pF |

Coupled Electrical Characteristics (Ta = 25°C)

| | | | AL | | |
|--------------------------------|--|--|---|--|--|
| Symbol | Test Condition | Min | Тур. | Max | Unit |
| I _C /I _F | IF = 5 mA, VCE = 5 V Rank GB | 50 100 | Ð | 400 400 | % |
| IC/IF(sat) | I _F = 1 mA, V _{CE} = 0.4 V Rank GB | 30 | 60 — | - | % |
| V _{CE(sat)} | $I_{C} = 2.4 \text{ mA}, I_{F} = 8 \text{ mA}$ $I_{C} = 0.2 \text{ mA}, I_{F} = 1 \text{ mA}$ | | — 0.2 | 0.3 | V |
| IC(off) | Rank GB VF = 0.7 V, VCE = 48 V | | 1 | 0.3 10 | μA |
| | IC/IF IC/IF(sat) VCE(sat) | I_{C}/I_{F} $I_{F} = 5 \text{ mA, } V_{CE} = 5 \text{ V}$ Rank GB $I_{C}/I_{F}(\text{sat})$ $I_{F} = 1 \text{ mA, } V_{CE} = 0.4 \text{ V}$ Rank GB $I_{C} = 2.4 \text{ mA, } I_{F} = 8 \text{ mA}$ $V_{CE}(\text{sat})$ $I_{C} = 0.2 \text{ mA, } I_{F} = 1 \text{ mA}$ Rank GB | $I_{C}/I_{F} = 5 \text{ mA, } V_{CE} = 5 V \qquad 50$ $I_{C}/I_{F} = 1 \text{ mA, } V_{CE} = 0.4 V \qquad 50$ $I_{C}/I_{F}(\text{sat}) = 1 \text{ mA, } V_{CE} = 0.4 V \qquad 700 \text{ mark GB} = 30$ $I_{C} = 2.4 \text{ mA, } I_{F} = 8 \text{ mA} \qquad -700 \text{ mark GB} = -700 \text{ mA}$ $V_{CE}(\text{sath}) = 1 \text{ mA} \qquad -700 \text{ mA}$ $I_{C} = 0.2 \text{ mA, } I_{F} = 1 \text{ mA} \qquad -700 \text{ mA}$ $I_{C} = 0.2 \text{ mA, } I_{F} = 1 \text{ mA} \qquad -700 \text{ mA}$ | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ |

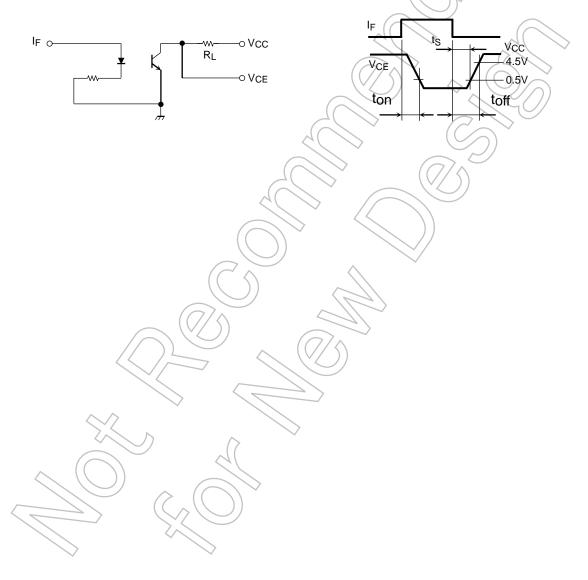
Isolation Characteristics (Ta = 25° C)

| | | 16-31 | | | | |
|-------------------------------|--------|------------------------|--------------------|------------------|-----|-------|
| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
| Capacitance (input to output) | Cs | Vs = 0 V, f = 1 MHz | — | 0.8 | _ | pF |
| Isolation resistance | Rs | Vs = 500 V, R.H. ≤ 60% | 1×10 ¹² | 10 ¹⁴ | _ | Ω |
| | | AC, 60 s | 3750 | _ | _ | Vrms |
| Isolation voltage | BVs | AC, 1 s, in oil | _ | 10000 | | VIII5 |
| | | DC, 60 s, in oil | — | 10000 | — | Vdc |

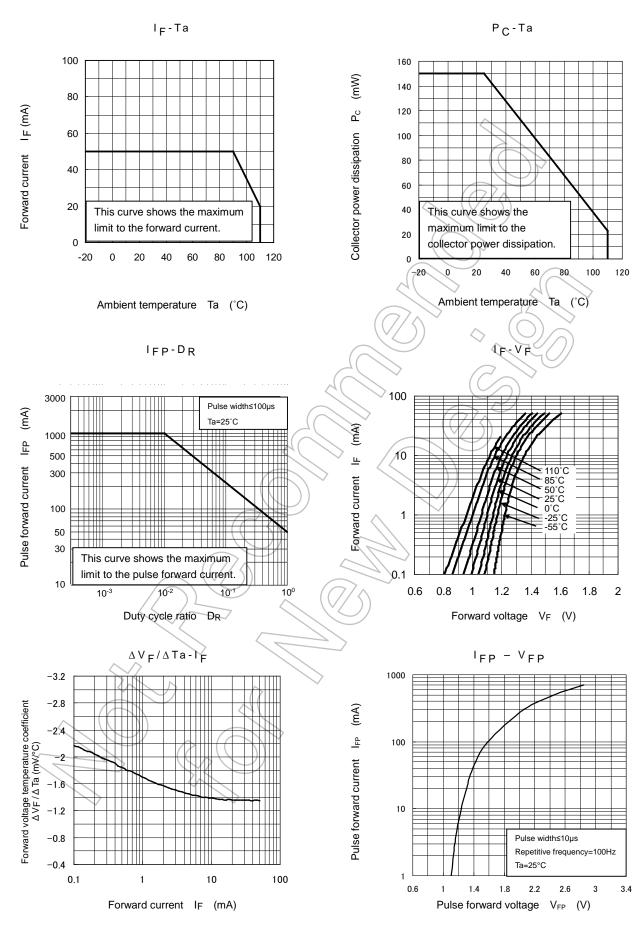
Switching Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------------|------------------|---|------------------|------|-----|------|
| Rise time | tr | | _ | 5 | — | μs |
| Fall time | tf | V _{CC} = 10 V, I _C = 2 mA | _ | 9 | — | |
| Turn-on time | t _{on} | $R_L = 100 \Omega$ | $\left \right $ | 9 | — | |
| Turn-off time | toff | | | 9 | — | |
| Turn-on time | ton | | F |) /2 | — | |
| Storage time | ts | $R_L = 1.9 kΩ$ (Fig.1) V _{CC} = 5 V, I _F = 16 mA | 77 | 30 | — | μs |
| Turn-off time | t _{off} | | \mathcal{A} | 70 | _ | |

Fig. 1 Switching time test circuit



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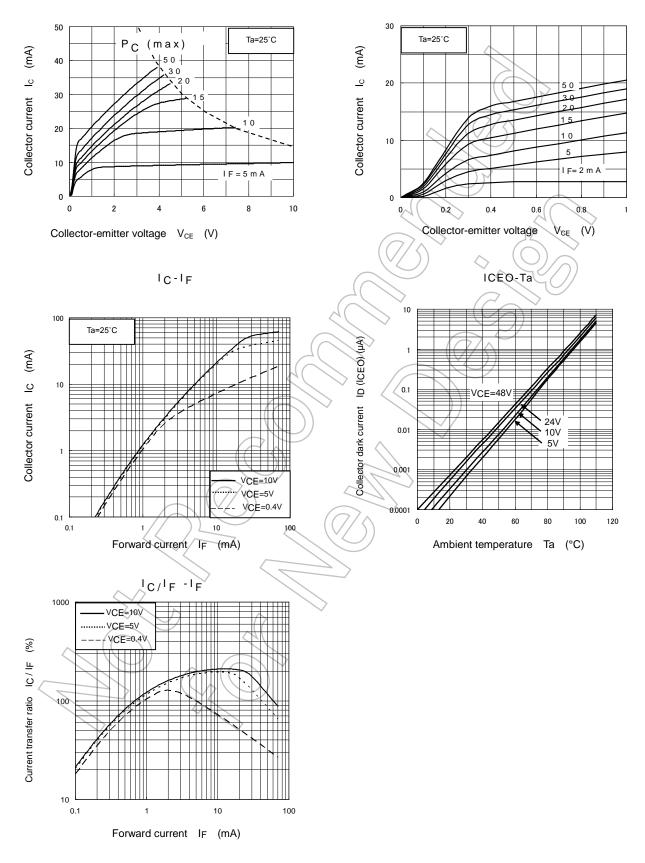


*The above graphs show typical characteristic.

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IC-VCE

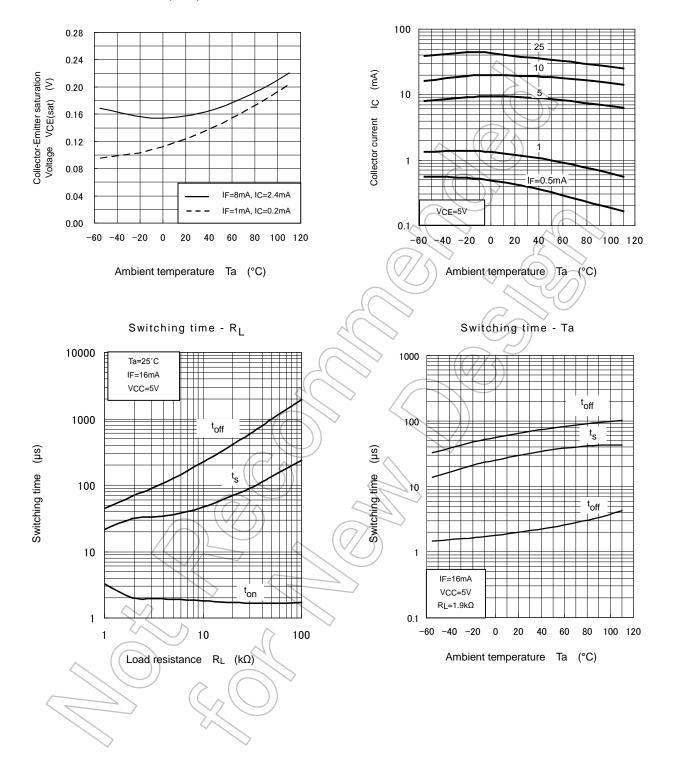




*The above graphs show typical characteristic.

V_{CE(sat)} – Ta

I_C - Ta



*The above graphs show typical characteristic.

Soldering and Storage

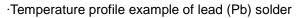
1. Soldering

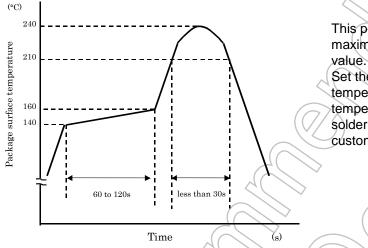
1.1 Soldering

When using a soldering iron or medium infrared ray/hot air reflow, avoid a rise in device temperature as

much as possible by observing the following conditions.

1) Using solder reflow

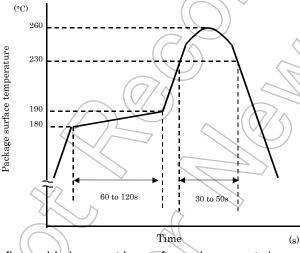




This profile is based on the device's maximum heat resistance guaranteed value. Set the preheat temperature/heating

temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

·Temperature profile example of using lead (Pb)-free solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

2) Using solder flow (for lead (Pb) solder, or lead (Pb)-free solder)

Please preheat it at 150°C between 60 and 120 seconds.

Complete soldering within 10 seconds below 260°C. Each pin may be heated at most once.

3) Using a soldering iron

Complete soldering within 10 seconds below 260°C, or within 3 seconds at 350°C. Each pin may be heated at most once.

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2. Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.

3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.

- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

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